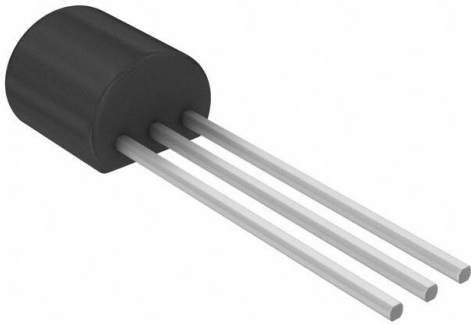


# FJN965BU Datasheet

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DiGi Electronics Part Number	FJN965BU-DG
Manufacturer	<a href="#">onsemi</a>
Manufacturer Product Number	FJN965BU
Description	TRANS NPN 20V 5A TO92-3
Detailed Description	Bipolar (BJT) Transistor NPN 20 V 5 A 150MHz 750 mW Through Hole TO-92-3



Tel: +00 852-30501935

RFQ Email: [Info@DiGi-Electronics.com](mailto:Info@DiGi-Electronics.com)

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## Purchase and inquiry

Manufacturer Product Number:

FJN965BU

Series:

-

Transistor Type:

NPN

Voltage - Collector Emitter Breakdown (Max):

20 V

Current - Collector Cutoff (Max):

1 $\mu$ A

Power - Max:

750 mW

Operating Temperature:

150°C (TJ)

Package / Case:

TO-226-3, TO-92-3 (TO-226AA)

Base Product Number:

FJN965

Manufacturer:

onsemi

Product Status:

Obsolete

Current - Collector (Ic) (Max):

5 A

Vce Saturation (Max) @ Ib, Ic:

1V @ 100mA, 3A

DC Current Gain (hFE) (Min) @ Ic, Vce:

230 @ 500mA, 2V

Frequency - Transition:

150MHz

Mounting Type:

Through Hole

Supplier Device Package:

TO-92-3

## Environmental & Export classification

Moisture Sensitivity Level (MSL):

1 (Unlimited)

ECCN:

EAR99

REACH Status:

REACH Unaffected

HTSUS:

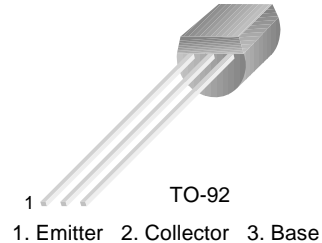
8541.21.0075

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## FJN965

### For Output Amplifier of Electronic Flash Unit

- Low Collector-Emitter Saturation Voltage
- High Performance at Low Supply Voltage



### NPN Epitaxial Silicon Transistor

#### Absolute Maximum Ratings $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Ratings	Units
$V_{CBO}$	Collector-Base Voltage	40	V
$V_{CEO}$	Collector-Emitter Voltage	20	V
$V_{EBO}$	Emitter-Base Voltage	7	V
$I_C$	Collector Current	5	A
$P_C$	Collector Dissipation	0.75	W
$T_J$	Junction Temperature	150	$^\circ\text{C}$
$T_{STG}$	Storage Temperature	-55 ~ 150	$^\circ\text{C}$

#### Electrical Characteristics $T_C=25^\circ\text{C}$ unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
$BV_{CEO}$	Collector-Emitter Voltage	$I_C=1\text{mA}, I_B=0$	20			V
$BV_{EBO}$	Emitter Base Voltage	$I_C=100\mu\text{A}, I_C=0$	7			V
$I_{CBO}$	Collector Cut-off Current	$V_{CB}=10\text{V}, I_E=0$			0.1	$\mu\text{A}$
$I_{CEO}$	Collector Cut-off Current	$V_{CE}=10\text{V}, I_B=0$			1	$\mu\text{A}$
$I_{EBO}$	Emitter Cut-off Current	$V_{EB}=7\text{V}, I_C=0$			0.1	$\mu\text{A}$
$h_{FE1}$ $h_{FE2}$	DC Current Gain	$V_{CE}=2\text{V}, I_C=0.5\text{A}$ $V_{CE}=2\text{V}, I_C=2\text{A}$	230 150		600	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage	$I_C=3\text{A}, I_B=0.1\text{A}$			1	V
$f_T$	Current Gain Band Width Product	$V_{CE}=6\text{V}, I_C=50\text{mA}$		150		MHz
$C_{ob}$	Collector Output Capacitance	$V_{CB}=20\text{V}, I_E=0, f=1\text{MHz}$		23		pF

# Typical Characteristics

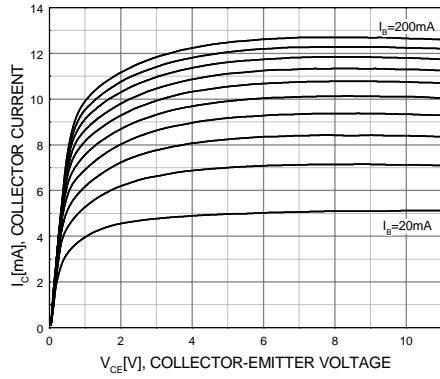


Figure 1. Static Characteristic

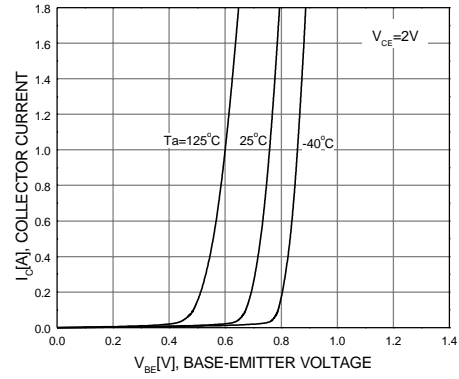


Figure 2. Base-Emitter On Voltage

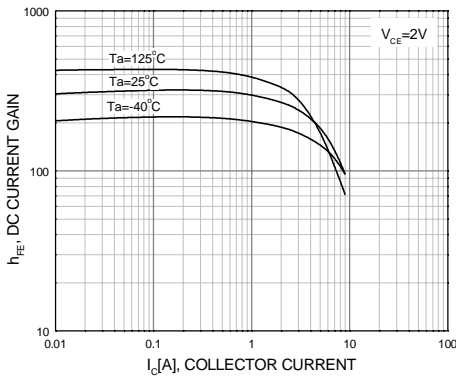


Figure 3. DC current Gain

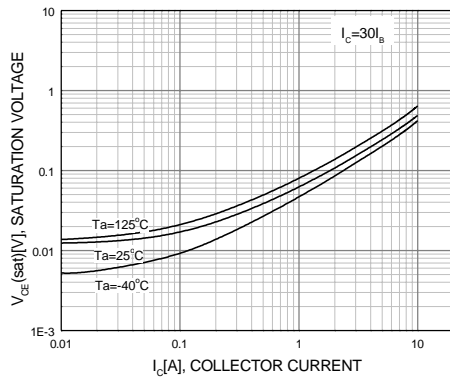


Figure 4. Collector-Emitter Saturation Voltage

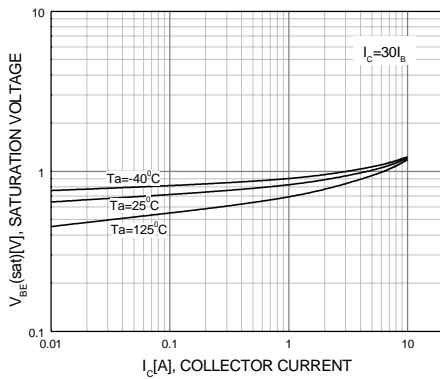


Figure 5. Base-Emitter On Voltage

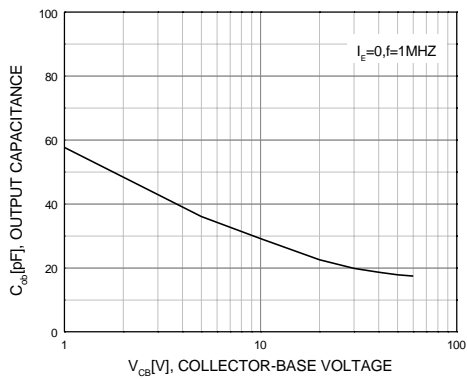


Figure 6. Collector Output Capacitance

Typical Characteristics (Continued)

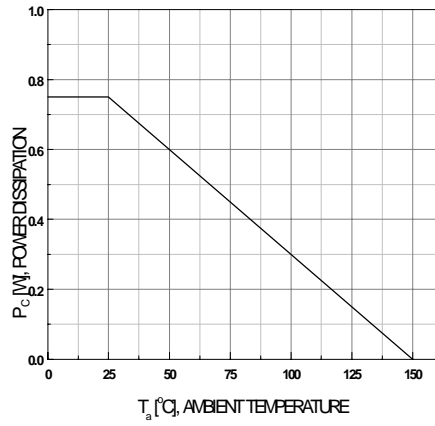


Figure 7. Power Derating

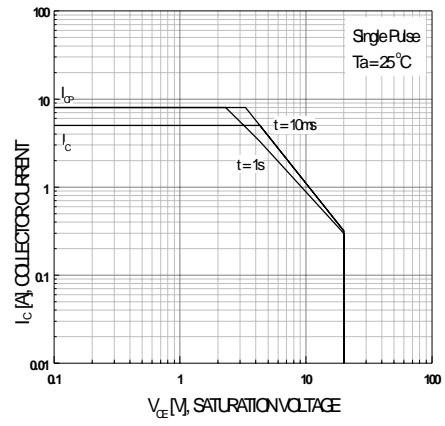
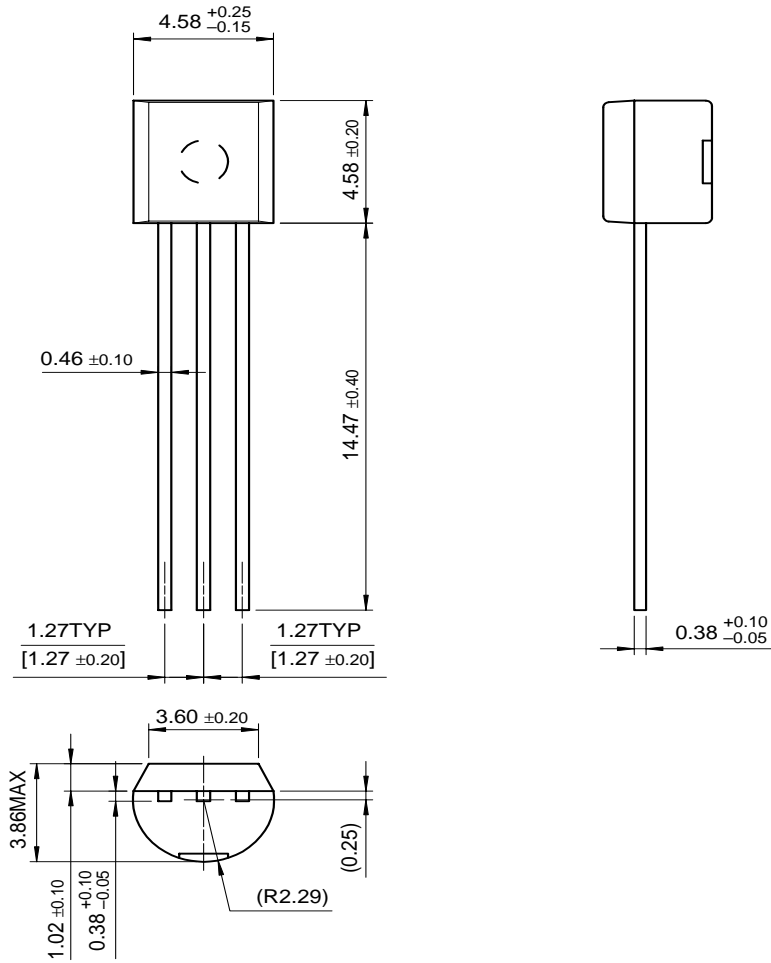


Figure 8. Forward Bias Safe Operating Area

**FJN965**

Package Dimensions

TO-92



Dimensions in Millimeters

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No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice in order to improve design.
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